

# Far-field nanoscale infrared spectroscopy of vibrational fingerprints of molecules with graphene plasmons

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Infrared spectroscopy, especially for molecular vibrations in the fingerprint region between 600 and 1,500 cm<sup>-1</sup>, is a powerful characterization method for bulk materials. However, molecular fingerprinting at the nanoscale level still remains a significant challenge, due to weak light-matter interaction between micron-wavelengthed infrared light and nano-sized molecules. Here we demonstrate molecular fingerprinting at the nanoscale level using our specially designed graphene plasmonic structure on CaF<sub>2</sub> nanofilm. This structure not only avoids the plasmon-phonon hybridization, but also provides *in situ* electrically-tunable graphene plasmon covering the entire molecular fingerprint region, which was previously unattainable. In addition, undisturbed and highly confined graphene plasmon offers simultaneous detection of in-plane and out-of-plane vibrational modes with ultrahigh detection sensitivity down to the sub-monolayer level, significantly pushing the current detection limit of far-field mid-infrared spectroscopies. Our results provide a platform, fulfilling the long-awaited expectation of high sensitivity and selectivity far-field fingerprint detection of nano-scale molecules for numerous applications.

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Far-field mid-infrared (MIR) spectroscopy has an increasingly important role for numerous applications (for example, chemical detection<sup>1</sup>, food safety<sup>2</sup> and bio-sensing<sup>3</sup>) through directly probing vibrational characteristics of a broad range of molecular species and compounds. In particular, in the molecular fingerprint region<sup>4–6</sup> from 600 to 1,500 cm<sup>−1</sup> (which corresponds to the wavelength range of  $\sim$ 6–16  $\mu$ m; (ref. 4), complex vibrational characteristics of molecules in bulk materials can be effectively distinguished to enable unambiguous identification of molecular structures and species<sup>4–6</sup>. Currently, high sensitivity and selectivity molecular detection at the nanoscale level in the fingerprint region is in great demand for various applications. However, as the wavelengths in this spectral range ( $\sim$ 10  $\mu$ m) approach lengths more than three orders of magnitude larger than typical molecules (approximately smaller than 10 nm), the light–molecule interaction cross-section becomes remarkably small<sup>7–9</sup>. Further, unique but complicated patterns of vibrational fingerprint modes produced by each different molecular components make selective identification difficult. These, therefore, yield extremely low sensitivity and selectivity detection of molecular vibrational fingerprints using infrared spectroscopy, which is insufficient to address ongoing challenges and emerging applications (for example, trace chemical detection and sensing for safety and health applications).

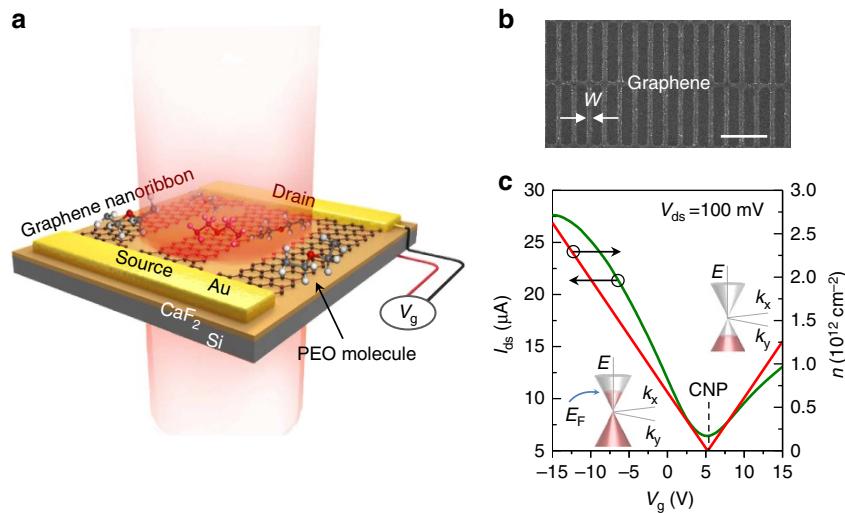
Plasmonic enhancement, one of the most effective approaches to improve light–matter interaction, has been implemented to enhance light–molecule interaction in the MIR range<sup>4,10–27</sup>. However, in contrast to its successful implementation in the visible and near-infrared spectral range, noble metal plasmons cannot fully fulfill the enhancement requirement in the molecular fingerprint region due to its weak field confinement, narrow spectral resonance and very limited tunability<sup>4,11–13</sup>. Recently, graphene has been demonstrated to manipulate electromagnetic signals at deep-subwavelength scale with ultrahigh field confinement due to its unique electronic band structures<sup>28–34</sup>. Especially, graphene plasmon resonance can be tuned by the structure dimensions and electrostatic doping in the terahertz and infrared region<sup>35–39</sup>. These extraordinary properties make graphene plasmon a promising candidate for detection

enhancement applications in the MIR region, which has been identified in recent experimental achievements<sup>8,40–45</sup>. However, in the technologically important MIR fingerprint region, graphene plasmon applications are severely restrained by strong coupling between the graphene plasmons and substrate phonons<sup>46–54</sup>, which strongly confines the electromagnetic energy between graphene and substrate. This results in low near-field enhancement on the graphene top surface and a limited spectral tunability, which are not suitable for sensing applications (for example, molecule fingerprint sensing).

Here we demonstrate a hybrid graphene plasmonic structure on a CaF<sub>2</sub> nanofilm (graphene/CaF<sub>2</sub>), in which there is no substrate phonon effect in the MIR region. This eliminates the strong plasmon–phonon coupling issue in conventional graphene plasmonic structures, and enables the first electrically tunable plasmon that covers the entire molecular fingerprint region for molecular detection with extremely high sensitivity down to sub-monolayer level. Highly selective average enhancement of up to larger than 20-fold is achieved for unambiguous identification of vibrational fingerprints in polymers at the nanoscale with a far-field Fourier transform infrared spectroscopy. In addition, our graphene plasmonic devices can simultaneously identify in-plane and out-of-plane vibrational modes in complicated molecules. Our results provide a route for highly sensitive and selective identification of molecular structure fingerprints for diverse applications in anti-terrorism, food and healthcare and bio-sensing.

## Results

**Graphene plasmonic device in the fingerprint region.** The design of our graphene-based molecular fingerprint sensor is illustrated in Fig. 1a. We introduce a 300-nm CaF<sub>2</sub> thin-film based dielectric supporting substrate for graphene (Fig. 1b,c), due to its broadband transparency in the infrared spectral region and suitable dielectric properties<sup>55</sup>. As shown in Fig. 2a (also Supplementary Fig. 1), CaF<sub>2</sub> does not exhibit any active phonon mode in the infrared region and provides a constant background in the fingerprint region of 675–1,500 cm<sup>−1</sup>, which is ideal for *in situ* spectroscopy in the MIR region<sup>10,38</sup>. In

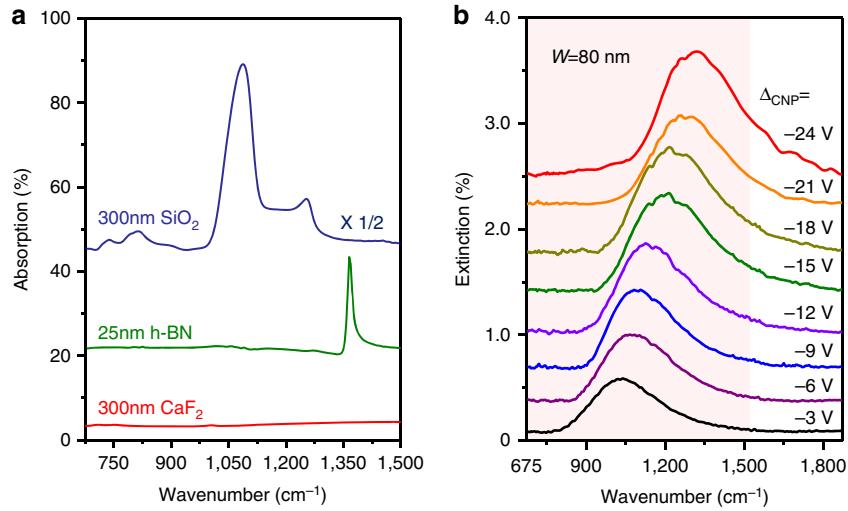


**Figure 1 | Graphene plasmon enhanced molecular fingerprint sensor.** (a) A schematic of the sensor. The graphene nanoribbon structure was designed on a CaF<sub>2</sub> dielectric substrate (300 nm thick). The graphene plasmon resonance excited by the incident infrared beam (the red shaded pillar) can be tuned *in situ* by electrostatic doping through the gate voltage ( $V_g$ ). (b) A scanning electron microscope image of the graphene nanoribbon pattern. Ribbon width ( $W$ ): 80 nm; width-to-pitch ratio: 1:3. Scale bar, 1  $\mu$ m. (c) The transfer curve (green line) of our graphene/CaF<sub>2</sub> fingerprint sensor. The gate voltage that corresponds to the charge neutral point (CNP,  $V_{\text{CNP}}$ , marked as dash line) is  $\sim$ 5 V.

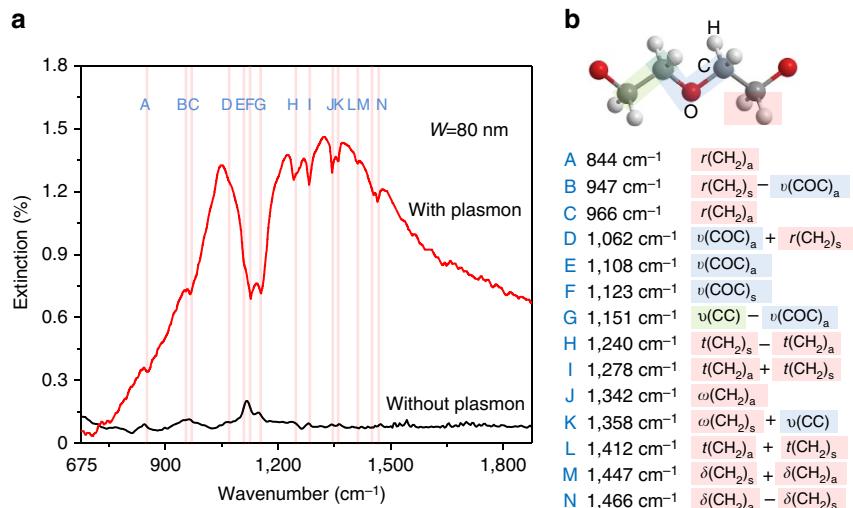
comparison, conventional  $\text{SiO}_2$  and hexagonal boron nitride (h-BN) substrates produce strong phonon-related resonance peaks in this spectral region (Fig. 2a). These phonons can strongly hybridize with graphene plasmon, and drastically reduce graphene plasmonic field enhancement and electrostatic tunability<sup>47,48</sup>. Further, in contrast to bulk  $\text{CaF}_2$  substrates<sup>10,38</sup> and diamond-like carbon substrates<sup>48</sup>, our  $\text{CaF}_2$  nanofilm is an excellent dielectric material for highly efficient graphene electrical doping<sup>56</sup>. Electrically continuous graphene nanoribbon arrays (Fig. 1b) connected with Au electrodes were fabricated on the  $\text{CaF}_2/\text{Si}$  substrate (see Methods and Supplementary Figs 2–5 for further details). The electrostatic tunability of our graphene/ $\text{CaF}_2$  device is shown in Fig. 1c. The graphene carrier density can be tuned up to  $2.6 \times 10^{12} \text{ cm}^{-2}$  with a relatively low gate voltage ( $V_g = -15 \text{ V}$ , as plotted in Fig. 1c), which

demonstrates effective dielectric isolation of the  $\text{CaF}_2$  thin film. The calculation of the carrier density and Fermi level is detailed in Supplementary Note 1.

A far-field Fourier transform infrared microscope (FTIR) was used to characterize the plasmonic response of graphene nanoribbons (see Methods for further details). Figure 2b shows the extinction spectra of a graphene nanoribbon array with an 80 nm ribbon width at various Fermi levels. As shown, the extinction spectra of our graphene/ $\text{CaF}_2$  device exhibit a single but prominent peak, while the graphene/ $\text{SiO}_2$  devices show multiple peaks due to the hybridization of plasmon and phonons (Supplementary Figs 6, 7). This indicates that the excellent intrinsic properties of the graphene plasmons were preserved in our graphene/ $\text{CaF}_2$  device without disturbance by the substrate phonons. By changing the graphene Fermi level within the gate



**Figure 2 | Optical properties of  $\text{CaF}_2$  nanofilm substrate.** (a) A comparison of the infrared absorption spectra of various dielectric substrates ( $\text{SiO}_2$ , h-BN and  $\text{CaF}_2$ ). (b) The broadband tunable intrinsic graphene plasmon in the graphene/ $\text{CaF}_2$  fingerprint sensor via the effective gate voltage ( $\Delta_{\text{CNP}} = V_g - V_{\text{CNP}}$ ). The red shaded region indicates the molecular fingerprint region.



**Figure 3 | Highly sensitive detection of molecular vibrational fingerprints.** (a) A comparison of the sensing results for an 8-nm-thick PEO film with (red curve) and without (black curve) graphene plasmon enhancement. The corresponding Fermi level is  $\sim 0.2 \text{ eV}$ . The red vertical lines indicate various PEO molecular vibrational modes. (b) The list of PEO vibrational modes in the molecular fingerprint region and their positions in a. The green, blue and red backgrounds represent the C-C, C-O-C, and methylene groups, respectively. The prefixes  $r$ ,  $\nu$ ,  $\omega$  and  $t$  indicate rocking, stretching, wagging and twisting modes, respectively. The suffixes  $s$  and  $a$  imply symmetric and anti-symmetric modes, respectively, with respect to the two-fold axis perpendicular to the helix axis and passing through the oxygen atom or center of the C-C bond. The + and - signs denote the phase relationship for the potential energy distribution of the coupled coordinates.

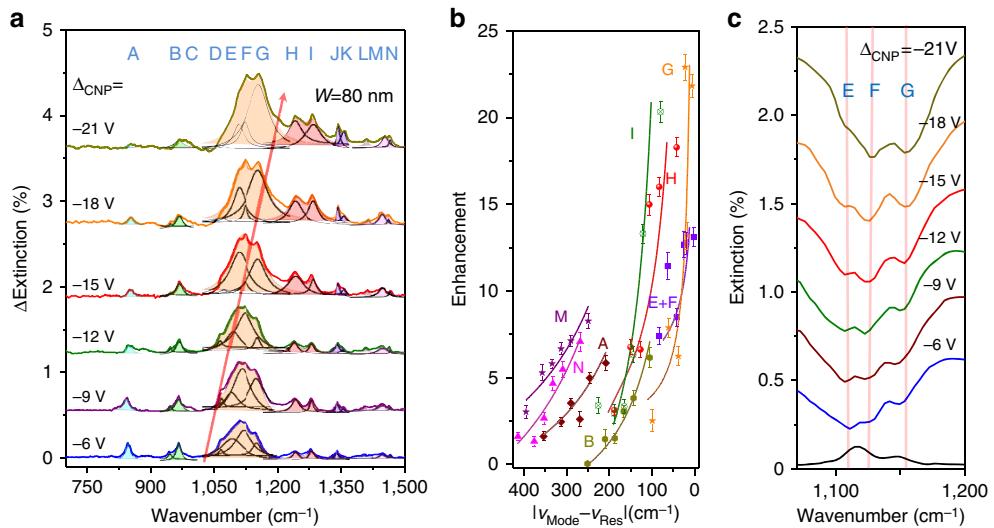
voltage change of  $\sim 21$  V, the plasmon resonance peak can be tuned over the  $900\text{--}1,400\text{ cm}^{-1}$  region. We can cover shorter and longer wavelength regions using graphene devices with different ribbon widths, as shown in Supplementary Figs 6 and 7. The graphene plasmon field confinement factor (defined by the wavelength ratio between the excitation light and graphene plasmon) was calculated at greater than 50, which indicates a large field enhancement in our graphene plasmonic molecular fingerprint sensors.

**High sensitivity and selectivity molecular fingerprinting.** To demonstrate the excellent performance of our molecular fingerprint sensors, we used ultrathin (8-nm-thick) polyethylene oxide (PEO) films as analyte because infrared spectra of PEO bulk films are well-studied and feature fourteen well-characterized molecular vibrational modes in the fingerprint region<sup>57</sup>. As shown in the pristine absorption spectrum (black curve in Fig. 3a) of an ultrathin PEO film (that is, without the graphene plasmon enhancement), the molecular vibrational absorption is weak (less than  $0.02\text{ nm}^{-1}$ ). Most absorption peaks cannot be distinguished from the background noise, which is expected from weak light–molecule interaction in this spectral range. In striking contrast to the noisy results without plasmon enhancement, the extinction spectrum (red curve in Fig. 3a) of the same PEO film covering the graphene nanoribbon array clearly features various strong dips over the broad graphene plasmon resonance after enhancement. These dips were assigned to fourteen molecular fingerprints of the PEO molecules, which correspond to various rocking, stretching, wagging and twisting molecular vibrational modes (Fig. 3b). These modes correlate well with previous infrared absorption results on bulk PEO films (Supplementary Fig. 8). The dip behaviours originate from destructive interference when the graphene plasmons and vibrational modes interact with an opposite phase relationship. We also compared the sensing results obtained with a  $\text{SiO}_2$  substrate (Supplementary Fig. 9),

which confirms that our  $\text{CaF}_2$  nanofilm indeed provides significant signal enhancement, due to the elimination of the strong plasmon–phonon coupling issue in conventional graphene plasmonic structures.

The vibrational mode signals close to the graphene plasmon resonance peak feature a much larger amplitude than those wing signals. For instance, the strength (defined by the peak area) of the mode F located at  $1,123\text{ cm}^{-1}$  (the strongest peak in the pristine polymer spectrum, which corresponds to the anti-symmetric stretching mode in the C–O–C group of the PEO molecules) has been enhanced by more than ten times (calculation details in Supplementary Fig. 10 and Supplementary Note 2). Considering that this is the average enhancement for the PEO film over the all detection area ( $0.2 \times 0.1\text{ mm}^2$ ) with a 1:3 graphene ribbon-to-pitch ratio, and the plasmonic field enhancement is strongly concentrated at the ribbon edges, the enhancement factor at the ribbon edges should be substantially larger than the average enhancement factor. We also tested the reusability of our plasmonic sensors (Supplementary Fig. 11 and Supplementary Note 3), which shows that our graphene devices are reusable and robust.

The graphene plasmon broadband electrical tunability offers unique frequency-selective enhancement for individual vibrational modes in our molecular fingerprint sensor as demonstrated by the plasmon-enhanced molecular fingerprinting results (Fig. 4a). For example, the graphene plasmon resonance frequency can be continuously tuned from  $1,052$  to  $1,198\text{ cm}^{-1}$  by changing  $\Delta_{\text{CNP}}$  from  $-6$  to  $-21$  V. The signal strengths of vibrational modes A and B gradually decrease when  $\Delta_{\text{CNP}}$  decreases from  $-6$  to  $-21$  V, which is expected because the graphene plasmon resonance frequency is tuned away from these modes. However, because the graphene plasmon resonance frequency is tuned towards the H, I, J and K modes, the signal intensities of these modes rapidly increase with a decrease in  $\Delta_{\text{CNP}}$ . To further investigate this frequency-selective function quantitatively, we fit the fourteen vibrational modes, extracted



**Figure 4 | Highly selective detection of molecular vibrational fingerprints.** (a) The plasmon-induced vibrational mode response of the PEO molecules extracted from the extinction spectra of the graphene plasmonic resonance peak at different effective gate voltages. The change of the center frequency of each plasmon peaks is indicated by the red arrow. The Lorentz line shapes (the thin solid curves) are used to fit the peaks induced by different vibrational modes of PEO molecules. The shaded areas with different colours indicate the superposition of the fitted peak areas. (b) The enhancement factor of typical vibrational modes as a function of the distance between the mode ( $v_{\text{Mode}}$ ) and graphene plasmon resonance peak ( $v_{\text{Res}}$ ). The error bars in the plots are standard deviation from large numbers of measurements. (c) Enlarged extinction spectra for the PEO ultra-thin films with and without plasmon enhancement in the range  $1,045\text{--}1,200\text{ cm}^{-1}$ . The pristine infrared absorption spectrum of the 8-nm PEO film without plasmon enhancement is shown as the black line at the bottom. The vertical lines indicate the positions of modes E, F and G.

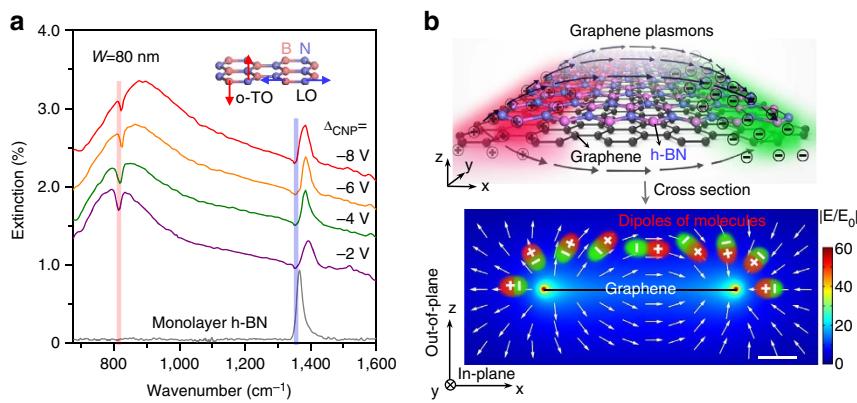
their peak areas and calculated their enhancement factors based on our experimental results (calculation details in Supplementary Note 2; (ref. 58). The calculated enhancement factors are shown in Fig. 4b (and Supplementary Fig. 12) as a function of the frequency difference ( $\Delta f$ ) between the vibrational mode and graphene plasmon. As expected, these fitted curves follow the fundamental principle of plasmonic enhancement: molecular signal enhancement ( $\Delta I$ ) is inversely proportional to the frequency detuning  $\Delta f$  ( $\Delta I \sim 1/\Delta f$ )<sup>40</sup>. This result demonstrates that the electrically tunable graphene plasmon can selectively enhance the vibrational modes. For instance, the overall enhancement factor of the mode G (at  $1,151\text{ cm}^{-1}$ , an interaction mode between the symmetric stretching of the C-C group and anti-symmetric stretching of the C-O-C group in the PEO molecules) can be adjusted from 2.5 to 23 via graphene plasmon frequency tuning.

In addition, with the electrical tunability enhancement, we can distinguish the overlapping vibrational modes in the pristine absorption spectrum. For example, the E and F modes cannot be distinguished in the absorption spectrum (Fig. 4c). However, the enhancement of modes E and F can be well modulated by electrically adjusting the graphene plasmon resonance frequency. In contrast to noble metal surface plasmons, which are typically tuned by changing the dimensions<sup>58</sup>, graphene plasmons with electrical tunability are superior for *in situ* frequency-selective enhancement and thus facilitate unambiguous identification of complex molecular compounds and structures through correlation with structural fingerprint detection.

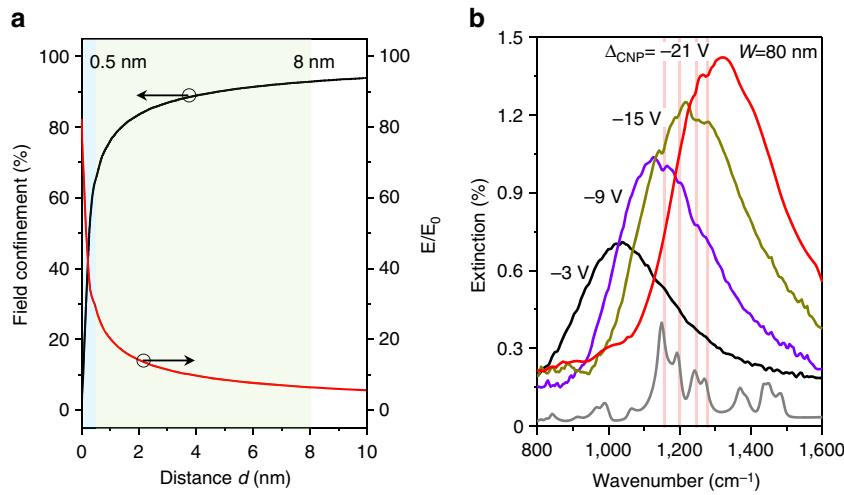
**Detection of in-plane and out-of-plane vibrational modes.** Here we demonstrated that our molecular fingerprint sensor can simultaneously perceive in-plane and out-of-plane vibrational modes. The out-of-plane modes (also named as ZO modes) are not typically visible for conventional infrared microscopy because these vibrational modes cannot respond to incident light with a polarization direction perpendicular to its vibrational direction<sup>57</sup>. To clarify this advantage, we choose h-BN monolayer as an example, which has both in-plane and

out-of-plane infrared modes<sup>59</sup>. Figure 5a shows the plasmonic enhanced infrared spectra of h-BN monolayer, as well as its pristine infrared absorption spectrum. The latter one only features the in-plane structure vibrational mode at  $\sim 1,370\text{ cm}^{-1}$  and the out-of-plane structure vibrational mode at  $\sim 820\text{ cm}^{-1}$  cannot be detected using the conventional infrared microscopy<sup>59</sup> (Supplementary Fig. 13). However, with the graphene plasmon enhancement, both the out-of-plane and in-plane vibrational modes in h-BN can be clearly detected (Fig. 5a). The sensing sensitivity (that is, the dip amplitude) is greatly enhanced (purple curve for a larger out-of-plane vibrational mode enhancement) with a good match between the graphene plasmonic resonance and vibrational mode after tuning the gate voltage. Such superior performance in detecting both the in-plane and out-of-plane vibrational modes is explained by the graphene plasmon enhancement effect in these directions<sup>51</sup>, as depicted schematically in Fig. 5b. As shown, the electric fields of graphene plasmons can follow along both the  $x$  and  $z$  directions, and their enhancements are comparable (Supplementary Fig. 14). Therefore, the in-plane and out-of-plane molecular vibrational modes can be possibly detected in our plasmonic sensor. Theoretical explanation on the coupling mechanism between the out-of-plane mode and the graphene plasmon is also given in Supplementary Fig. 15 and Supplementary Note 4. This unique property, wherein multi-directional vibrational modes are accessed (that is, the out-of-plane and in-plane modes), provides a promising approach for probing sophisticated changes in molecular configurations, such as protein folding or molecular crystallization at interfaces.

**Detection of sub-monolayer polymer.** In principle, highly confined graphene plasmons can facilitate high-sensitivity, sub-monolayer detection. On the basis of near-field distribution, we calculated near-field intensity confinement as a function of a given distance  $d$  from the graphene ribbons (Fig. 6a). The data shows that  $\sim 65\%$  of the plasmon energy is confined within a  $0.5\text{ nm}$  gap from the graphene surface, which suggests possible plasmon enhancement for sensing trace elements with



**Figure 5 | Simultaneous detection of in-plane and out-of-plane vibrational fingerprints.** (a) The extinction spectra (coloured lines) of the graphene plasmon sensor covered with an h-BN monolayer. The infrared extinction spectrum (grey line) of monolayer BN is obtained with incident light normal to the h-BN basal plane. The vertical lines indicate the positions of the optical phonon modes of h-BN monolayer. Inset: the out-of-plane (the transverse optical phonon mode at  $\sim 820\text{ cm}^{-1}$ , o-TO) and in-plane (the longitudinal optical phonon mode at  $\sim 1,370\text{ cm}^{-1}$ , LO) modes in h-BN. (b) A schematic diagram of the interaction between the electric field of the graphene plasmon and monolayer h-BN structure vibrations. The red and green colours in the upper figure indicate the snapshot of positive and negative charge distribution of graphene plasmon. The black arrows represent graphene plasmon. The lower part shows the side view of the electric field intensity distribution calculated from  $100\text{ nm}$  wide graphene nanoribbons with  $E_F = 0.3\text{ eV}$ , obtained from a finite element electromagnetic simulation. White arrows indicate the relative direction of the distribution of electric field of graphene plasmon and the response of molecular vibrations to the plasmonic electric field is illustrated by dipoles. The colour bar indicates the field confinement of graphene plasmon, while  $E_0$  is the electric field intensity of incident light. Scale bar,  $20\text{ nm}$ .



**Figure 6 | Sub-monolayer polymer molecules detection.** (a) Near-field intensity confinement and near-field enhancement as a function of the distance  $d$  from the graphene nanoribbons. The shaded regions correspond to  $d < 0.5$  and  $8\text{ nm}$ , respectively.  $E_0$  is the electric field intensity of incident light. (b) The sub-monolayer residual PMMA polymer extinction spectra enhanced by the graphene plasmon sensor at different effective gate voltages for molecular vibrational fingerprinting. An absorption spectrum of a 300-nm thick PMMA film (the extinction strength is decreased 10 times) is provided to indicate the PMMA vibrational fingerprint modes. Vertical lines indicate four strong vibrational fingerprints of PMMA.

dimensions as small as  $0.5\text{ nm}$ . For verification, we performed sensing experiments on a residual polymethyl methacrylate (PMMA) polymer during the device fabrication process of our graphene device. Generally, a PMMA monolayer is  $\sim 4\text{ nm}$  thick<sup>60</sup>, but a residual PMMA layer is typically a discontinuous sub-monolayer film with a maximum thickness  $<1.5\text{ nm}$  (Supplementary Fig. 3). Such sub-monolayer films cannot be detected through conventional infrared microscopy due to its low sensitivity. The extinction spectra of the residual PMMA on our molecular fingerprint sensor at varied effective gate voltages are shown in Fig. 6b. As shown, the PMMA vibrational fingerprint modes at  $1,151, 1,192, 1,244$  and  $1,269\text{ cm}^{-1}$ , can be identified in the prominent plasmon resonant peaks<sup>61</sup>. Because the amount of the PMMA molecules is extremely small, their infrared signals become very weak and even invisible when the detuning between molecular vibrational peaks and the plasmon peak is large (for example, when  $\Delta_{\text{CNP}} = -3\text{ V}$ ). Thanks to the electrical tunability of graphene plasmon, we can tune its resonance with the gate voltage to selectively identify the vibrational fingerprints of sub-monolayer polymer (for example, the ones corresponding to  $\Delta_{\text{CNP}}$  of  $-9$  and  $-15\text{ V}$ ). These observations clearly indicate that our molecular fingerprint sensor is highly sensitive and selective even for sub-monolayer molecules detection.

## Discussion

In conclusion, we demonstrate high sensitivity and selectivity molecular fingerprinting with a graphene plasmon based far-field Fourier transform infrared spectroscopy. We enhance  $\sim 8\text{-nm}$  PEO film vibrational signatures up to larger than 20-fold. We also show that our method can detect structural vibrational modes (both the in-plane and out-of-plane structural vibrations) in molecules with a resolution previously unachievable using conventional mid-infrared absorption spectroscopy. Our graphene plasmon based far-field molecular fingerprint spectroscopy can facilitate various applications, such as functional studies on trace matter in biology and pharmacology.

## Methods

**Device preparation.** Graphene and monolayer h-BN were grown on copper foil through chemical vapour deposition methods and transferred onto a  $\text{SiO}_2$  ( $285\text{ nm}$ )/Si substrate using the PMMA-assisted method. Nanoribbon arrays were

patterned onto the graphene surface using electron beam lithography (Vistec 5000 + ES, Germany) in PMMA followed by oxygen plasma etching. An additional electron beam lithography process and electron beam evaporation were used to define the electrodes. We deposited a  $300\text{-nm}$  thick  $\text{CaF}_2$  film onto a low-doped Si substrate using electron beam evaporation. The complete graphene device was then transferred onto the  $\text{CaF}_2$ /Si substrate. A thin ( $\sim 8\text{ nm}$ ) PEO polymer layer was spin-coated onto the sensor as a sensing sample.

**Characterization.** Patterned graphene nanoribbons were characterized with scanning electron microscopy (Hitachi S-4800) and atomic force microscopy (Neespec s-SNOM). The graphene quality was confirmed by Raman spectroscopy (Horiba Jobin Yvon LabRAM HR800) before and after oxygen ion bombardment under PMMA protection. The electrical transport properties were characterized using a semiconductor parameter analyser (Agilent 4294A) at room temperature.

**FTIR microscopy measurements.** Infrared transmission measurements were performed using a FTIR microscope (Thermo Fisher Nicolet iN10). We generated a background spectrum for each measurement. A bare  $\text{CaF}_2$ /Si substrate was used to extract the background signal from the pristine PEO film absorption spectrum. The graphene nanoribbon array transmission spectra at CNP ( $T_{\text{CNP}}$ ) were used as background, and the transmission spectra ( $T_{\text{EF}}$ ) at certain Fermi levels  $E_{\text{F}}$  were collected to obtain the plasmonic extinction spectra by  $1 - T_{\text{EF}}/T_{\text{CNP}}$ . Thus, the extinction spectra are purely plasmonic signals excited by the incident light. Each measurement was repeated several times to confirm the extinction spectrum.

**Simulation.** The graphene plasmons were simulated by using the finite element method. The infrared lights impinge perpendicular on graphene nanoribbons. We modelled graphene as a thin film with a thickness of  $t$  and imposed the relative permittivity  $\epsilon_{\text{G}} = -i\sigma/\omega\epsilon_0 t$ .  $\sigma(\omega)$  is the complex optical conductivity of graphene evaluated within the local random phase approximation<sup>62</sup>. The graphene thickness is set to be  $1\text{ nm}$ , at which the calculations reach proper convergence.

**Data availability.** The data that support the findings of this study are available from the corresponding author upon request.

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## Acknowledgements

We thank Javier Aizpurua and Tomáš Neuman for useful discussion of the theoretical simulation. Z.S. thanks Amos Martinez for his comments on the manuscript. This work was supported by the National Basic Research Program of China (grant no. 2015CB932400), the National Natural Science Foundation of China (grant no. 51372045, 11504063, 11174252, 11474006, 51522201 and 9143102), the International Science and Technology Cooperation Project (no. 2014DFR10780, China), the Academy of Finland (grant no: 276376, 284548, 295777), TEKES (OPEC), Nokia foundation, and the European Union's Seventh Framework Programme (REA grant agreement no. 631610).

## Author contributions

Q.D. and X.Y. conceived the experiments; H.H. performed the device fabrication, characterization and FTIR measurements; F.Z. provided modelling and the

theoretical studies; D.H. performed atomic force microscopy characterization and near-field infrared image measurements; R.L. helped in device fabrication and FTIR measurements; H.H. X.Y., Q.D., Z.S. and K.L. analysed the data and co-wrote the manuscript.